

2N6426G Information

Heisener.com

Part Number 2N6426G

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

DescriptionTRANS NPN DARL 40V 0.5A TO92**Package**TO-226-3, TO-92-3 (TO-226AA)

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N6426G Specifications	
Manufacturer Part Number	2N6426G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-226-3, TO-92-3 (TO-226AA)
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	500mA
Voltage - Collector Emitter Breakdown (Max)	40V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 500μA, 500mA
Current - Collector Cutoff (Max)	1μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	30000 @ 100mA, 5V
Power - Max	625mW
Frequency - Transition	-
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 (TO-226AA)
Supplier Device Package	TO-92-3
	Report errors?

2N6426G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N6426G Payment Methods





















2N6426G Shipping Methods













If you have any question about 2N6426G, please do not hesitate to contact us!

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